

产品规格书 DATA SHEET

Part No: MHP5050ICRGBCT REV.1

本产品符合 ROHS 指令有关限制有害物质的环保要求.

日期 DATE	拟制 PREPARED	审核 VERIFIED	批准 APPROVED
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	连云港美华电子科技有限公司					
	P/N:MHP5050ICRGBC	т	LED PLCC			
Parameter L	imitation(Unless otherwise specif	ied: Ta=25℃,V	DD=5.0V,VSS=0V)			
	参数	符号	极限值	单位		
	Parameter	Symbol	Rating	Unit		
	芯片电源电压 Chip Supply Voltage	VDD	3.0~7.5	V		
输入电压 Input Voltage		Vin	-0.5~5.5	V		
GRE	GRB 输出驱动电流 3 Output Driving Current	lo	15	mA		
	功率 Power	PD	400	mW		
	PWM	Fрwм	3~5	kHz		
	工作温度 Work Temp	Topt	-40~85	°C		
	储存温度 Storage Temp.	Tstg	-40~85	°C		

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	P/N:MH	P5050ICR	GBCT	L	ED PLC	C
lectrical Cha	racteristic	S (Ta=-40~+85	°C, VDD=3. 0V	~7.5V,VSS=0V)		
参数	符号	最小	典型	最大	单位	备注
Parameter	Symbol	Min	Тур	Max	Unint	Note
芯片电源电压	VDD	3	5	7.5	V	
Chip supply Voltage						
睡眠电流	ISLEEP	0.6	0.8	1	mA	
Sleep Current						
高电平输入	V_{IH}	VDD*0.7		VDD	V	Din
High-level Input 低电平输入	VIL	0		VDD*0.3	V	Din
Low-level Input	V IL	0			,	DIII
GRB 最大吸收	I_{sink}		12	15	mA	VDD-VfLED
电流						≥ 1.2V
G、 R、 B Maximum Sink						
current						







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Function and Sequential Description

1. 编码顺序 Coding Sequence

MCU 数据通过单线总线接口与芯片通信。通信协议采用极性归零码模式,每个码必须具有低电平。该通信协议中每个代码的起始级别为高级别,高级别的时间宽度区分 "0"代码或 "1"代码。

MCU data is communicated with chip through single wire bus interface. The communication protocol adopts polarity return to zero code mode, and each codes must have low level. The starting level of each codes in this communication protocol is high level, and the time width of high level distinguish "0" code or "1" code.

Name	Description	Min.	Тур.	Max.	Tolerance	Unit
тон	0 Code, high level time		0.295		0.05	us
T1H	1 Code,high level time		0.595		0.05	us
TOL	0 Code, Low level time		0.595		0.05	us
T1L	1 Code, low level time		0.295		0.05	us
Trst	Reset code low level time	80				us

2. 协议数据格式 Protocol Data Format

根据该原理,第一芯片的 Trst+24 位数据+第二芯片的 24 位数据+····+第 N 芯片 24 位数 据+Trst A 24 位灰度级数据结构: 前部高字节,以G、R 和 B 顺序发送数据 According to the Principle, Trst + 24-bit data for first chip + 24-bit data for second chip +... + Nth chip 24-bit data +Trst A 24-bit grey-scale data structure: high bytes in front part, sends data with G, R, and B order







Temperature curve features	leaded solder	Lead-free solder	
Average heating rate (TSmax to TP)	Max 3℃/second	Max 3°C/second	
Preheating: minimum temperature (Tsmin)	100 ℃	150℃	
Preheating: maximum temperature (Tsmax)	150 ℃	200 ℃	
Warm-up: time (Tsmin to Tsmax)	60-120 seconds	60-120 seconds	
Time to maintain high temperature: Temperature (TL)	183℃	217 ℃	
Time to maintain high temperature: Time (tL)	60-150 seconds	60-150 seconds	
Peak/Classification temperature (TP)	215 ℃	245 ℃	
Time at actual peak temperature (TP) 5℃	<10 seconds	<10seconds	
Cooling speed	Max 6℃/Second	Max 6°C/Second	
Time required to reach peak temperature from 25℃	Max 6min.	Max 6min.	

Time

Note: All temperatures are measured on the surface of the package body



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储藏 STORAGE

1. 发光二极管在出厂后可在温度 30 度以下,湿度 60%以下的环境内保存 1 年。The LED should be stored at 30℃ or less and 60% RH or less after being shipped from MH and the storage life limits are 1 year.

2. 在产品准备使用前请不要打开防潮袋。Do not open moisture proof bag before the products are ready to use.

3. 打开包装后:产品暴露在温度 30 度以下湿度 60%以下的 24 小时内用完,若仍然有剩余,请一定要放到防潮柜内储存。After opening the package: The LED's floor life is 24 hr under 30℃ or less and 60% RH or less. If unused LEDs remain, it should be stored in moisture proof packages.

4. 如果吸湿性材料(硅胶)已用完或发光二极管已超过存储时间,应使用以下条件进行 烘烤处理,处理: 60±5℃烘烤 5 小时。If the moisture absorbent material (silica gel) has faded away or the LEDs have exceeded the storage time,baking treatment should be performed using the following conditions.Baking treatment: 60±5℃ for 5 hours.

3. 请避免保存在温度变化明显,尤其是高湿度的地方 Please avoid rapid transitions in ambient temperature, especially, in high humidity environments where condensation can occur.

使用注意事项 Application Restrictions

1. 生产环境: 建议在 20℃~30℃&30%~60%RH 下作业。 Production environment: it is recommended to operate at 20 DEG ~30 DEG &30%~60%RH

2. 维修温度建议控制在 280℃以下,持续加热时间不超过 30S。 The service temperature shall be controlled below 280 degrees, and the continuous heating time shall not exceed 30S.

3. 维修时避免尖锐物体直接戳到胶体,取料时建议夹取板材两端。

When repairing, the sharp object should be directly punched into the colloid, and when picking the material, it is recommended to clamp both ends of the PCB.



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其他注意事项 Others

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4. 静电放电(静电放电) ESD (Electrostatic Discharge

产品敏感的静电或冲击电压。当使用产品时静电放电会损坏模具及其可靠性。对静电放电的措施强烈推荐消除电荷接地的手环,防静电鞋,衣服和地板等 The products are sensitive to static electricity or surge voltage. ESD can damage a die and its reliability. When handling the products, the following measures against electrostatic discharge are strongly recommended:Eliminating the charge Grounded wrist strap, ESD footwear, clothes, and floors

5. 发光二极管正向电流方向使用,驱动电路的设计必须使 LED 在关闭的状态下不经受 正向或逆向电压,如果反向电压不断应用于发光二极管,它可以导致 LED 损坏。 cause migration resulting in LED damage.

The LEDs should be operated with forward bias. The driving circuit must be designed so that the LEDs are not subjected to forward or reverse voltage while it is off. If reverse voltage is continuously applied to the LEDs, it may cause migration resulting in LED damage.